

# Xuyong Yang

## List of Publications by Year in descending order

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105  
papers

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citations

101543

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110387

64  
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107  
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107  
docs citations

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times ranked

4771  
citing authors

#	ARTICLE	IF	CITATIONS
1	Efficient Tandem Quantum-Dot LEDs Enabled by An Inorganic Semiconductor-Metal-Dielectric Interconnecting Layer Stack. <i>Advanced Materials</i> , 2022, 34, e2108150.	21.0	53
2	Efficient Tandem Quantum-Dot LEDs Enabled by An Inorganic Semiconductor-Metal-Dielectric Interconnecting Layer Stack (Adv. Mater. 4/2022). <i>Advanced Materials</i> , 2022, 34, .	21.0	0
3	All-Inorganic Perovskite Nanocrystals with Remarkably Enhanced Optoelectronic Properties Realized by an Alkene-Free Solvent Strategy and Their Electroluminescence. <i>Advanced Optical Materials</i> , 2022, 10, .	7.3	2
4	Efficient all-inorganic perovskite light-emitting diodes with a multifunctional potassium bromide doped hole transport layer. <i>Optical Materials Express</i> , 2022, 12, 1708.	3.0	2
5	Suppressing the Cation Exchange at the Core/Shell Interface of InP Quantum Dots by a Selenium Shielding Layer Enables Efficient Green Light-Emitting Diodes. <i>ACS Applied Materials &amp; Interfaces</i> , 2022, 14, 15401-15406.	8.0	18
6	Light-emitting field-effect transistors with EQE over 20% enabled by a dielectric-quantum dots-dielectric sandwich structure. <i>Science Bulletin</i> , 2022, 67, 529-536.	9.0	23
7	Perovskite nanocrystals-polymer composites with a micro/nano structured superhydrophobic surface for stable and efficient white light-emitting diodes. <i>Chemical Engineering Journal</i> , 2022, 437, 135303.	12.7	20
8	A Multifunctional Ionic Liquid Additive Enabling Stable and Efficient Perovskite Light-Emitting Diodes. <i>Small</i> , 2022, 18, e2200498.	10.0	24
9	Enhancing the Light Output-Coupling of Inverted Top-Emitting Organic Light-Emitting Diodes by Using the Localized Surface Plasmon Resonance of Ag Nanoparticles. <i>Advanced Materials Interfaces</i> , 2022, 9, .	3.7	4
10	A mixed solvent strategy enabling efficient all-solution-processed perovskite light-emitting diodes. <i>Journal of Materials Chemistry C</i> , 2022, 10, 8964-8971.	5.5	2
11	Boosting the efficiency and stability of green InP quantum dot light emitting diodes by interface dipole modulation. <i>Journal of Materials Chemistry C</i> , 2022, 10, 8192-8198.	5.5	12
12	Mixed-Dimensional MXene-Based Composite Electrodes Enable Mechanically Stable and Efficient Flexible Perovskite Light-Emitting Diodes. <i>Nano Letters</i> , 2022, 22, 4246-4252.	9.1	24
13	Quasi-Shell-Growth Strategy Achieves Stable and Efficient Green InP Quantum Dot Light-Emitting Diodes. <i>Advanced Science</i> , 2022, 9, .	11.2	33
14	Amine-Terminated Carbon Dots Linking Hole Transport Layer and Vertically Oriented Quasi-2D Perovskites through Hydrogen Bonds Enable Efficient LEDs. <i>ACS Nano</i> , 2022, 16, 9679-9690.	14.6	41
15	On the accurate characterization of quantum-dot light-emitting diodes for display applications. <i>Npj Flexible Electronics</i> , 2022, 6, .	10.7	8
16	The solution-processed fabrication of perovskite light-emitting diodes for low-cost and commercial applications. <i>Journal of Materials Chemistry C</i> , 2021, 9, 12037-12045.	5.5	7
17	Halide perovskite based light-emitting diodes: a scaling up perspective. <i>Journal of Materials Chemistry C</i> , 2021, 9, 7532-7538.	5.5	7
18	Smoothing the energy transfer pathway in quasi-2D perovskite films using methanesulfonate leads to highly efficient light-emitting devices. <i>Nature Communications</i> , 2021, 12, 1246.	12.8	274

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19	Solvent-Regulated Electronic Structure and Morphology of Inorganic Hole Injection Layers for Efficient Quantum Dot Light-Emitting Diodes. <i>Advanced Photonics Research</i> , 2021, 2, 2000124.	3.6	5
20	All-Inorganic Quantum Dot Light-Emitting Diodes with Suppressed Luminance Quenching Enabled by Chloride Passivated Tungsten Phosphate Hole Transport Layers. <i>Small</i> , 2021, 17, e2100030.	10.0	33
21	Low-Threshold Amplified Spontaneous Emission in Blue Quantum Dots Enabled by Effectively Suppressing Auger Recombination. <i>Advanced Optical Materials</i> , 2021, 9, 2100068.	7.3	8
22	Core/Shell Metal Halide Perovskite Nanocrystals for Optoelectronic Applications. <i>Advanced Functional Materials</i> , 2021, 31, 2100438.	14.9	67
23	Editorial: Advanced Nanomaterials for Light-Emitting Diodes and Solar Cells. <i>Frontiers in Chemistry</i> , 2021, 9, 741760.	3.6	1
24	A Study on Solution-Processed Y <sub>2</sub> O <sub>3</sub> Films Modified by Atomic Layer Deposition Al <sub>2</sub> O <sub>3</sub> as Dielectrics in ZnO Thin Film Transistor. <i>Coatings</i> , 2021, 11, 969.	2.6	6
25	37.1: Invited Paper: High Color-purity Light-Emitting Diodes Based on Quantum dots/perovskites. <i>Digest of Technical Papers SID International Symposium</i> , 2021, 52, 477-477.	0.3	0
26	A seed-mediated and double shell strategy to realize large-size ZnSe/ZnS/ZnS quantum dots for high color purity blue light-emitting diodes. <i>Nanoscale</i> , 2021, 13, 4562-4568.	5.6	23
27	Boosting Efficiency of InP Quantum Dots-Based Light-Emitting Diodes by an In-Doped ZnO Electron Transport Layer. <i>IEEE Electron Device Letters</i> , 2021, 42, 1806-1809.	3.9	15
28	Blue light-emitting diodes based on halide perovskites: Recent advances and strategies. <i>Materials Today</i> , 2021, 51, 222-246.	14.2	64
29	Efficient All-Solution-Processed Perovskite Light-Emitting Diodes Enabled by Small-Molecule Doped Electron Injection Layers. <i>Advanced Optical Materials</i> , 2020, 8, 1900567.	7.3	25
30	Metal Halide Perovskite Nanorods: Shape Matters. <i>Advanced Materials</i> , 2020, 32, e2002736.	21.0	48
31	Metal Halide Perovskites: Metal Halide Perovskite Nanorods: Shape Matters ( <i>Adv. Mater.</i> 46/2020). <i>Advanced Materials</i> , 2020, 32, 2070348.	21.0	1
32	Boosting the Efficiency of NiO <sub>x</sub> -Based Perovskite Light-Emitting Diodes by Interface Engineering. <i>ACS Applied Materials &amp; Interfaces</i> , 2020, 12, 53528-53536.	8.0	32
33	A Multi-functional Molecular Modifier Enabling Efficient Large-Area Perovskite Light-Emitting Diodes. <i>Joule</i> , 2020, 4, 1977-1987.	24.0	111
34	Improving Efficiency and Stability in Quasi-2D Perovskite Light-Emitting Diodes by a Multifunctional LiF Interlayer. <i>ACS Applied Materials &amp; Interfaces</i> , 2020, 12, 43018-43023.	8.0	53
35	Applying InP/ZnS Green-Emitting Quantum Dots and InP/ZnSe/ZnS Red-Emitting Quantum Dots to Prepare WLED With Enhanced Photoluminescence Performances. <i>IEEE Access</i> , 2020, 8, 154683-154690.	4.2	4
36	Promoted Hole Transport Capability by Improving Lateral Current Spreading for High-Efficiency Quantum Dot Light-Emitting Diodes. <i>Advanced Science</i> , 2020, 7, 2001760.	11.2	30

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37	Core/Shell Perovskite Nanocrystals: Synthesis of Highly Efficient and Environmentally Stable FAPbBr <sub>3</sub> /CsPbBr <sub>3</sub> for LED Applications. <i>Advanced Functional Materials</i> , 2020, 30, 1910582.	14.9	135
38	Atomically thin heavy-metal-free ZnTe nanoplatelets formed from magic-size nanoclusters. <i>Nanoscale Advances</i> , 2020, 2, 3316-3322.	4.6	9
39	Surface modification of all-inorganic halide perovskite nanorods by a microscale hydrophobic zeolite for stable and sensitive laser humidity sensing. <i>Nanoscale</i> , 2020, 12, 13360-13367.	5.6	21
40	Lattice Distortion in Mixed-Anion Lead Halide Perovskite Nanorods Leads to their High Fluorescence Anisotropy. , 2020, 2, 814-820.		33
41	Hybrid plasmonic nano-emitters with controlled single quantum emitter positioning on the local excitation field. <i>Nature Communications</i> , 2020, 11, 3414.	12.8	33
42	Low-Voltage Hf-ZnO Thin Film Transistors With Ag Nanowires Gate Electrode and Their Application in Logic Circuit. <i>IEEE Journal of the Electron Devices Society</i> , 2020, 8, 152-156.	2.1	5
43	Energy Level Modification with Carbon Dot Interlayers Enables Efficient Perovskite Solar Cells and Quantum Dot Based Light-Emitting Diodes. <i>Advanced Functional Materials</i> , 2020, 30, 1910530.	14.9	72
44	Molecule-Induced p-Doping in Perovskite Nanocrystals Enables Efficient Color-Saturated Red Light-Emitting Diodes. <i>Small</i> , 2020, 16, e2001062.	10.0	53
45	Ten-Gram-Scale Synthesis of FAPbX <sub>3</sub> Perovskite Nanocrystals by a High-Power Room-Temperature Ultrasonic-Assisted Strategy and Their Electroluminescence. <i>Advanced Materials Technologies</i> , 2020, 5, 1901089.	5.8	16
46	Excitonic optical properties of cesium trifluoroacetate induced CsPbBr <sub>3</sub> thin film with anti-solvent treatment. <i>Optical Materials</i> , 2020, 106, 110005.	3.6	8
47	All-solution processed inverted green quantum dot light-emitting diodes with concurrent high efficiency and long lifetime. <i>Materials Horizons</i> , 2019, 6, 2009-2015.	12.2	66
48	Stable, Strongly Emitting Cesium Lead Bromide Perovskite Nanorods with High Optical Gain Enabled by an Intermediate Monomer Reservoir Synthetic Strategy. <i>Nano Letters</i> , 2019, 19, 6315-6322.	9.1	101
49	High-performance light-soaking-free polymer solar cells based on a LiF modified ZnO electron extraction layer. <i>Journal of Materials Chemistry C</i> , 2019, 7, 9354-9361.	5.5	18
50	Solution-processed ZnO/MoS <sub>2</sub> quantum dots electron extraction layer for high performance inverted organic photovoltaics. <i>Organic Electronics</i> , 2019, 75, 105381.	2.6	11
51	InP quantum dots-based electroluminescent devices. <i>Chinese Physics B</i> , 2019, 28, 118103.	1.4	7
52	Efficient and Stable Inverted Quantum Dot Light-Emitting Diodes Enabled by An Inorganic Copper-Doped Tungsten Phosphate Hole-Injection Layer. <i>ACS Applied Materials &amp; Interfaces</i> , 2019, 11, 40267-40273.	8.0	22
53	44.3: <i>Invited Paper:</i> Solution-processed inorganic charge transport layers for efficient and stable quantum-dot LEDs. <i>Digest of Technical Papers SID International Symposium</i> , 2019, 50, 490-490.	0.3	0
54	Towards all-solution-processed top-illuminated flexible organic solar cells using ultrathin Ag-modified graphite-coated poly(ethylene terephthalate) substrates. <i>Nanophotonics</i> , 2019, 8, 297-306.	6.0	22

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55	Stepwise Bi-Layer Hole-Transport Interlayers With Deep Highest Occupied Molecular Orbital Level for Efficient Green Quantum Dot Light-Emitting Diodes. <i>IEEE Electron Device Letters</i> , 2019, 40, 1139-1142.	3.9	10
56	Trifluoroacetate induced small-grained CsPbBr <sub>3</sub> perovskite films result in efficient and stable light-emitting devices. <i>Nature Communications</i> , 2019, 10, 665.	12.8	350
57	Ultrastable Inorganic Perovskite Nanocrystals Coated with a Thick Long-Chain Polymer for Efficient White Light-Emitting Diodes. <i>Chemistry of Materials</i> , 2019, 31, 1936-1940.	6.7	107
58	High color rendering index white LEDs fabricated using InP/ZnS green-emitting quantum dots and InP/ZnSe/ZnS red-emitting quantum dots. , 2019, , .		0
59	Synthesis and electroluminescence of novel white fluorescence quantum dots based on a Znâ€“Gaâ€“S host. <i>Chemical Communications</i> , 2019, 55, 14206-14209.	4.1	8
60	Trimethylsilyl Iodine-Mediated Synthesis of Highly Bright Red-Emitting CsPbI <sub>3</sub> Perovskite Quantum Dots with Significantly Improved Stability. <i>Chemistry of Materials</i> , 2019, 31, 881-889.	6.7	88
61	Solution-Processed Double-Junction Quantum-Dot Light-Emitting Diodes with an EQE of Over 40%. <i>ACS Applied Materials &amp; Interfaces</i> , 2019, 11, 1065-1070.	8.0	44
62	3D Photoluminescent Nanostructures Containing Quantum Dots Fabricated by Twoâ€“Photon Polymerization: Influence of Quantum Dots on the Spatial Resolution of Laser Writing. <i>Advanced Materials Technologies</i> , 2019, 4, 1800522.	5.8	35
63	Recent advances in quantum dot-based light-emitting devices: Challenges and possible solutions. <i>Materials Today</i> , 2019, 24, 69-93.	14.2	213
64	Fast Postmoisture Treatment of Luminescent Perovskite Films for Efficient Lightâ€“Emitting Diodes. <i>Small</i> , 2018, 14, e1703410.	10.0	35
65	High-efficiency all-inorganic full-colour quantum dot light-emitting diodes. <i>Nano Energy</i> , 2018, 46, 229-233.	16.0	52
66	Bright violet-to-aqua-emitting cadmium-free Ag-doped Znâ€“Gaâ€“S quantum dots with high stability. <i>Chemical Communications</i> , 2018, 54, 4176-4179.	4.1	13
67	Efficient Deep-Blue Electrofluorescence with an External Quantum Efficiency Beyond 10%. <i>IScience</i> , 2018, 9, 532-541.	4.1	65
68	A Layer-by-Layer Growth Strategy for Large-Size InP/ZnSe/ZnS Coreâ€“Shell Quantum Dots Enabling High-Efficiency Light-Emitting Diodes. <i>Chemistry of Materials</i> , 2018, 30, 8002-8007.	6.7	159
69	Highâ€“Efficiency, Solutionâ€“Processed White Quantum Dot Lightâ€“Emitting Diodes with Serially Stacked Red/Green/Blue Units. <i>Advanced Optical Materials</i> , 2018, 6, 1800652.	7.3	48
70	Nitrogen-Doped ZnO Film Fabricated Via Rapid Low-Temperature Atomic Layer Deposition for High-Performance ZnON Transistors. <i>IEEE Transactions on Electron Devices</i> , 2018, 65, 3283-3290.	3.0	22
71	Highly efficient, all-solution-processed, flexible white quantum dot light-emitting diodes. <i>Journal of Materials Chemistry C</i> , 2018, 6, 9642-9648.	5.5	38
72	Highly bright and stable white-light-emitting cadmium-free Ag,Mn co-doped Znâ€“Inâ€“S/ZnS quantum dots and their electroluminescence. <i>Journal of Materials Chemistry C</i> , 2018, 6, 10233-10240.	5.5	13

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73	High Efficiency and Stable Quantum Dot Light-Emitting Diodes Enabled by a Solution-Processed Metal-Doped Nickel Oxide Hole Injection Interfacial Layer. <i>Advanced Functional Materials</i> , 2017, 27, 1704278.	14.9	114
74	White-light-emitting Cu,Mn co-doped Zn <sup>2+</sup> /In <sup>3+</sup> /ZnS quantum dots with high stability and their electroluminescence. <i>Journal of Materials Chemistry C</i> , 2017, 5, 10533-10542.	5.5	30
75	Synthesis of WO <sub>3</sub> /WX <sub>2</sub> (X=S, Se) Heterostructures for Highly Efficient Green Quantum Dot Light-Emitting Diodes. <i>Angewandte Chemie</i> , 2017, 129, 10622-10626.	2.0	7
76	Synthesis of WO <sub>3</sub> /WX <sub>2</sub> (X=S, Se) Heterostructures for Highly Efficient Green Quantum Dot Light-Emitting Diodes. <i>Angewandte Chemie - International Edition</i> , 2017, 56, 10486-10490.	13.8	21
77	Iodide capped PbS/CdS core-shell quantum dots for efficient long-wavelength near-infrared light-emitting diodes. <i>Scientific Reports</i> , 2017, 7, 14741.	3.3	32
78	LEDs: High Efficiency and Stable Quantum Dot Light-Emitting Diodes Enabled by a Solution-Processed Metal-Doped Nickel Oxide Hole Injection Interfacial Layer ( <i>Adv. Funct. Mater.</i> 42/2017). <i>Advanced Functional Materials</i> , 2017, 27, .	14.9	0
79	Small-size and monodispersed red-emitting Pr <sup>3+</sup> doped barium molybdate nanocrystals with ultrahigh color purity. <i>RSC Advances</i> , 2016, 6, 65311-65314.	3.6	11
80	Improved quantum dot light-emitting diodes with a cathode interfacial layer. <i>Organic Electronics</i> , 2016, 32, 89-93.	2.6	31
81	Electroluminescence Efficiency Enhancement in Quantum Dot Light-Emitting Diodes by Embedding a Silver Nanoisland Layer. <i>Advanced Optical Materials</i> , 2015, 3, 1439-1445.	7.3	59
82	A quinoxaline based N-heteroacene interfacial layer for efficient hole-injection in quantum dot light-emitting diodes. <i>Nanoscale</i> , 2015, 7, 11531-11535.	5.6	22
83	Colloidal quantum-dot LEDs with a solution-processed copper oxide (CuO) hole injection layer. <i>Organic Electronics</i> , 2015, 26, 245-250.	2.6	53
84	Two-Color Single Hybrid Plasmonic Nanoemitters with Real Time Switchable Dominant Emission Wavelength. <i>Nano Letters</i> , 2015, 15, 7458-7466.	9.1	35
85	Transition metal oxides on organic semiconductors. <i>Organic Electronics</i> , 2014, 15, 871-877.	2.6	30
86	Stable, Efficient, and All-Solution-Processed Quantum Dot Light-Emitting Diodes with Double-Sided Metal Oxide Nanoparticle Charge Transport Layers. <i>ACS Applied Materials &amp; Interfaces</i> , 2014, 6, 495-499.	8.0	66
87	Solution Processed Tungsten Oxide Interfacial Layer for Efficient Hole-Injection in Quantum Dot Light-Emitting Diodes. <i>Small</i> , 2014, 10, 247-252.	10.0	96
88	Light-Emitting Diodes: Solution Processed Tungsten Oxide Interfacial Layer for Efficient Hole-Injection in Quantum Dot Light-Emitting Diodes ( <i>Small</i> 2/2014). <i>Small</i> , 2014, 10, 246-246.	10.0	4
89	Light Extraction Efficiency Enhancement of Colloidal Quantum Dot Light-Emitting Diodes Using Large-Scale Nanopillar Arrays. <i>Advanced Functional Materials</i> , 2014, 24, 5977-5984.	14.9	68
90	Highly Flexible, Electrically Driven, Top-Emitting, Quantum Dot Light-Emitting Stickers. <i>ACS Nano</i> , 2014, 8, 8224-8231.	14.6	135

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91	Quantum Dot Light-Emitting Diode with Quantum Dots Inside the Hole Transporting Layers. ACS Applied Materials & Interfaces, 2013, 5, 6535-6540.	8.0	42
92	AC-driven, color- and brightness-tunable organic light-emitting diodes constructed from an electron only device. Organic Electronics, 2013, 14, 3195-3200.	2.6	36
93	Facile Synthesis of Luminescent AgInS <sub>2</sub> /ZnS Solid Solution Nanorods. Small, 2013, 9, 2689-2695.	10.0	32
94	High-quality InP/ZnS nanocrystals with high photometric performance and their application to white quantum dot light-emitting diodes. , 2012, , .		1
95	A bright cadmium-free, hybrid organic/quantum dot white light-emitting diode. Applied Physics Letters, 2012, 101, .	3.3	64
96	Full Visible Range Covering InP/ZnS Nanocrystals with High Photometric Performance and Their Application to White Quantum Dot Light-Emitting Diodes. Advanced Materials, 2012, 24, 4180-4185.	21.0	283
97	Bifunctional highly fluorescent hollow porous microspheres made of BaMoO <sub>4</sub> :Pr <sup>3+</sup> nanocrystals via a template-free synthesis. Journal of Materials Chemistry, 2011, 21, 9009.	6.7	24
98	Europium (II)-Doped Microporous Zeolite Derivatives with Enhanced Photoluminescence by Isolating Active Luminescence Centers. ACS Applied Materials & Interfaces, 2011, 3, 4431-4436.	8.0	43
99	Self-Assembly and Photoluminescence Characterization of CaMoO <sub>4</sub> :Eu <sup>3+</sup> ,Na <sup>+</sup> Superstructure via a Facile Surfactant-Free Hydrothermal Method. Journal of the Electrochemical Society, 2011, 158, K74.	2.9	19
100	Photoluminescence of Eu <sup>2+</sup> -activated NaAl <sub>1-x</sub> Al <sub>1+x</sub> Si <sub>1-x</sub> O <sub>4</sub> upon UV excitation. Journal of Rare Earths, 2010, 28, 34-36.	4.8	21
101	Investigation of near infrared reflectance by tuning the shape of SnO <sub>2</sub> nanoparticles. Journal of Alloys and Compounds, 2010, 496, 261-264.	5.5	62
102	A Promising Deep Red Phosphor AgLaMo <sub>2</sub> O <sub>8</sub> :Pr <sup>3+</sup> with Blue Excitation for White LED Application. Journal of the Electrochemical Society, 2010, 157, H278.	2.9	22
103	The investigation of optical properties by doping halogen in the BaMoO <sub>4</sub> :Pr <sup>3+</sup> phosphor system. Journal of Alloys and Compounds, 2009, 479, 307-309.	5.5	39
104	Preparation and optical properties of Eu <sup>3+</sup> /Eu <sup>2+</sup> in phosphors based on exchanging Eu <sup>3+</sup> -zeolite 13X. Journal of Alloys and Compounds, 2009, 480, 867-869.	5.5	16
105	Synthesis and characterization of new red phosphors for white LED applications. Journal of Materials Chemistry, 2009, 19, 3771.	6.7	123